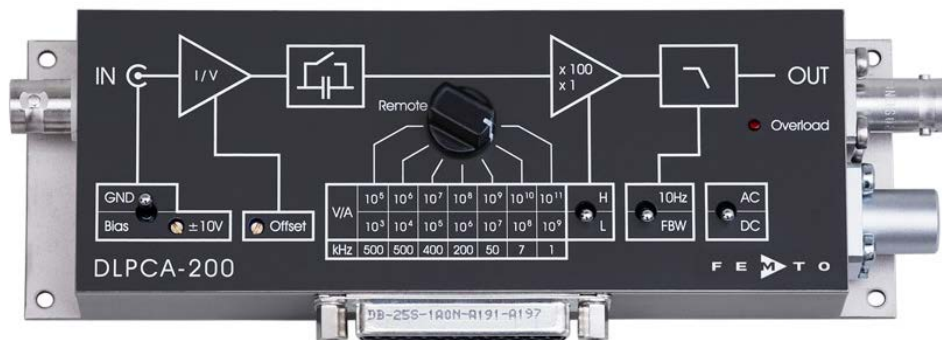


CURRENT / TRANSIMPEDANCE AMPLIFIERS

Ultra-Low-Noise Amplifiers
For High-Speed Precision Measurements



CURRENT AMPLIFIERS

VOLTAGE AMPLIFIERS

GHZ-WIDEBAND
AMPLIFIERS

PHOTORECEIVERS

LOCK-IN AMPLIFIERS

ACCESSORIES

SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

DDPCA-300 Variable Gain Ultra-Low-Noise Current Amplifier

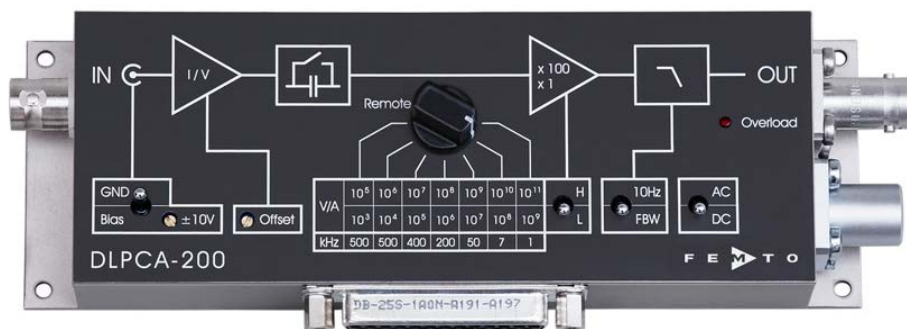


- 0.4 fA peak-to-peak noise
- Variable transimpedance gain from 10^4 to 10^{13} V/A
- 240 dB dynamic range for sub-fA to mA measurements
- Adjustable bias voltage
- Compact and highly EMI-shielded case for use close to the signal source
- Manual and remote control

APPLICATIONS

Photo and ionization detector amplifier | I/V characterization of MOS and JFET structures | measurement of ultra-low currents | Quantum and biotech experiments | Spectroscopy | High resistance measurements | Easy-to-use FEMTO® amplifier add-on to existing digital voltmeter or A/D converter

DLPCA-200 Variable Gain Low-Noise Current Amplifier

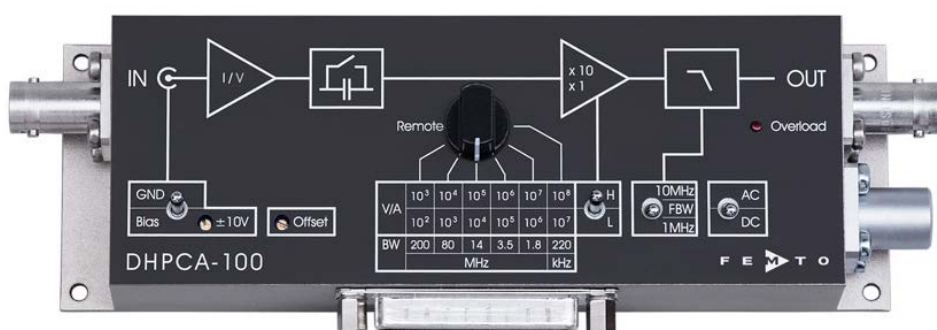


- Variable transimpedance gain from 10^3 to 10^{11} V/A
- Input noise down to $4.3 \text{ fA}/\sqrt{\text{Hz}}$
- Bandwidth up to 500 kHz
- Rise time down to 700 ns
- Adjustable bias voltage
- Manual and remote control

APPLICATIONS

Photodetector amplifier | Scanning tunneling microscopy (STM) | Spectroscopy | Beam monitoring for particle accelerators/synchrotrons | Ionization detectors | Preamplifier for lock-ins, A/D converters, etc.

DHPCA-100 Variable Gain High-Speed Current Amplifier



- Variable transimpedance gain from 10^2 to 10^8 V/A
- Bandwidth up to 200 MHz
- Rise time down to 1.8 ns
- Adjustable bias voltage
- Manual and remote control

APPLICATIONS

Photodetector amplifier | Fast ionization detection | Spectroscopy | Preamplifier for oscilloscopes, A/D converters and RF lock-in amplifiers

For detailed information about DDPCA-300, DLPCA-200, and DHPCA-100 see next page!

DDPCA-300 Sub-Femto Ampere Sensitivity

Model	DDPCA-300									
Transimpedance [V/A]	10 ⁴	10 ⁵	10 ⁶	10 ⁷	10 ⁸	10 ⁹	10 ¹⁰	10 ¹¹	10 ¹²	10 ¹³
Bandwidth* (-3 dB) [Hz]	400	400	400	400	150	150	20	20	1	1
Rise Time* (10 % - 90 %) [ms]	0.8	0.8	0.8	0.8	2.3	2.3	17	17	350	350
Equ. Input Noise [$\sqrt{\text{Hz}}$]	45 pA	45 pA	0.45 pA	0.45 pA	15 fA	15 fA	1.3 fA	1.3 fA	0.2 fA	0.2 fA
Accuracy	Transimpedance (Gain) ± 1 %									
Low Pass Filter	3 settings: full bandwidth, 0.7 Hz and 0.1 Hz									
Output Range	± 10 V, ± 30 mA									
Bias Voltage Range	± 10 V, max. 10 mA, connected to amplifier input, adjustable by trimpot or remote control voltage									
Power Supply	± 15 V, +70 mA / -15 mA typ.									
Control Interface	4 opto-isolated digital inputs, TTL/CMOS compatible, analog voltage input for bias control									
Case	170 x 60 x 45 mm (L x W x H), weight 320 g (0.74 lbs)									

* The values for bandwidth, rise time and integrated input noise stated in the table above are achieved with the low pass filter set to full bandwidth. Lower noise values can be achieved by setting the low pass filter to 0.7 Hz or 0.1 Hz. The minimum of 0.4 fA peak-to-peak noise is achieved in the gain settings 10¹² and 10¹³ V/A with the low pass filter set to 0.1 Hz.

Offset adjustable by potentiometer. Overload indication by LED and digital control output. Input protected against ± 2 kV transients. Output short-circuit protected. Power supply via 3-pin Lemo® socket, a mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet or contact FEMTO®.

DLPCA-200 Broad Application Range

Model	DLPCA-200													
Performance Range	Low Noise							High Speed						
Transimpedance [V/A]	10 ³	10 ⁴	10 ⁵	10 ⁶	10 ⁷	10 ⁸	10 ⁹	10 ⁵	10 ⁶	10 ⁷	10 ⁸	10 ⁹	10 ¹⁰	10 ¹¹
Bandwidth (-3 dB) [kHz]	500	500	400	200	50	7	1.1	500	500	400	200	50	7	1.1
Rise Time (10 % - 90 %)	700 ns	700 ns	900 ns	1.8 μ s	7 μ s	50 μ s	300 μ s	700 ns	700 ns	900 ns	1.8 μ s	7 μ s	50 μ s	300 μ s
Equ. Input Noise [$\sqrt{\text{Hz}}$]	20 pA	2.3 pA	450 fA	130 fA	43 fA	13 fA	4.3 fA	13 pA	1.8 pA	440 fA	130 fA	43 fA	13 fA	4.3 fA
Accuracy	Transimpedance (Gain) ± 1 %													
Low Pass Filter	2 settings: full bandwidth and 10 Hz													
Output Range	± 10 V, ± 30 mA													
Bias Voltage Range	± 10 V, max. 22 mA, connected to shield of BNC input socket, switchable to GND													
Power Supply	± 15 V, +120 mA / -80 mA typ.													
Control Interface	5 opto-isolated digital inputs, TTL/CMOS compatible, analog voltage input for offset control													
Case	170 x 60 x 45 mm (L x W x H), weight 320 g (0.74 lbs)													

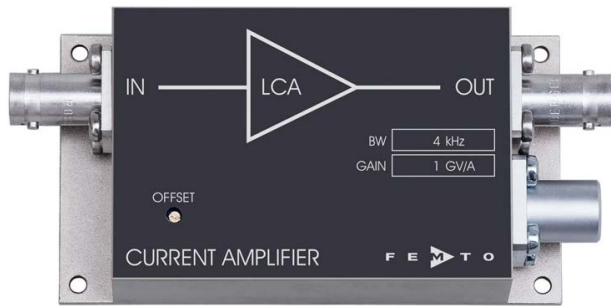
Offset adjustable by potentiometer or external control voltage. LED overload indication. Input protected against ± 3 kV transients. Output short-circuit protected. Power supply via 3-pin Lemo® socket, a mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet or contact FEMTO®.

DHPCA-100 MHz Speed

Model	DHPCA-100											
Performance Range	Low Noise						High Speed					
Transimpedance [V/A]	10 ²	10 ³	10 ⁴	10 ⁵	10 ⁶	10 ⁷	10 ³	10 ⁴	10 ⁵	10 ⁶	10 ⁷	10 ⁸
Bandwidth (-3 dB) [MHz]	200	80	14	3.5	1.8	0.22	175	80	14	3.5	1.8	0.22
Rise Time (10 % - 90 %)	1.8 ns	4.4 ns	25 ns	0.1 μ s	0.2 μ s	1.6 μ s	2.0 ns	4.4 ns	25 ns	0.1 μ s	0.2 μ s	1.6 μ s
Equ. Input Noise [$\sqrt{\text{Hz}}$]	220 pA	17 pA	2.2 pA	490 fA	140 fA	51 fA	155 pA	6.1 pA	1.5 pA	440 fA	140 fA	51 fA
Accuracy	Transimpedance (Gain) ± 1 %											
Low Pass Filter	3 settings: full bandwidth, 10 MHz and 1 MHz											
Output Range	± 1 V @ 50 Ω load											
Bias Voltage Range	± 10 V, max. 22 mA, connected to BNC-shield, switchable to GND											
Power Supply	± 15 V, +110 mA / -90 mA											
Control Interface	7 opto-isolated digital inputs, TTL/CMOS compatible, analog voltage input for offset control											
Case	170 x 60 x 45 mm (L x W x H), weight 320 g (0.74 lbs)											

Offset adjustable by potentiometer or external control voltage. LED overload indication. Input protected against ± 3 kV transients. Output short-circuit protected. Power supply via 3-pin Lemo® socket, a mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet or contact FEMTO®.

LCA Series Ultra Low-Noise Current Amplifier



- Input noise down to 180 aA/√Hz
- Bandwidth up to 400 kHz
- Gain up to 10¹³ V/A
- Flat frequency response
- EMI-shielded case

APPLICATIONS

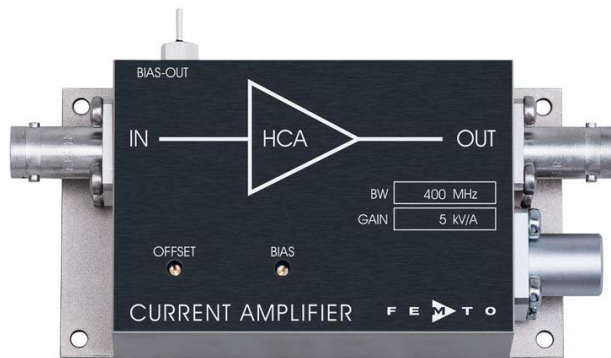
Photodetector amplifier | Spectroscopy | Scanning tunneling microscopy (STM) | Ionization detectors | Pyro- and piezoelectric detectors

Model	-3 dB Bandwidth (DC ...)	Noise Current [fA/√Hz]	Transimpedance (Gain)	Rise/Fall Time
LCA-2-10T	2 Hz	0.18 fA	10 ¹² and 10 ¹³ V/A	200 ms
LCA-30-1T	30 Hz	0.5 fA	1 x 10 ¹² V/A	12 ms
LCA-30-200G	30 Hz	0.5 fA	2 x 10 ¹¹ V/A	12 ms
LCA-200-100G	200 Hz	1.5 fA	1 x 10 ¹¹ V/A	2 ms
LCA-200-10G	200 Hz	1.5 fA	1 x 10 ¹⁰ V/A	2 ms
LCA-1K-5G	1 kHz	3 fA	5 x 10 ⁹ V/A	400 μs
LCA-2K-2G	2 kHz	4.5 fA	2 x 10 ⁹ V/A	200 μs
LCA-4K-1G	4 kHz	6.5 fA	1 x 10 ⁹ V/A	100 μs
LCA-10K-500M	10 kHz	10 fA	5 x 10 ⁸ V/A	40 μs
LCA-20K-200M	20 kHz	14 fA	2 x 10 ⁸ V/A	20 μs
LCA-40K-100M	40 kHz	19 fA	1 x 10 ⁸ V/A	10 μs
LCA-100K-50M	100 kHz	30 fA	5 x 10 ⁷ V/A	4 μs
LCA-200K-20M	200 kHz	40 fA	2 x 10 ⁷ V/A	2 μs
LCA-400K-10M	400 kHz	65 fA	1 x 10 ⁷ V/A	1 μs

NOTE: Bandwidth and frequency response are independent of detector capacitance. Guaranteed and 100 % tested up to 10 nF for each amplifier (up to 1 nF for LCA-400K-10M).

Output voltage ±10 V @ >10 kΩ load. Offset adjustable by trimpot. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet or contact FEMTO®.

HCA Series High-Speed Current Amplifier



- Input noise down to 270 fA/√Hz
- Bandwidth up to 400 MHz
- Gain up to 10⁶ V/A
- Flat frequency response
- Stabilized and adjustable bias voltage output for biasing external photodiodes
- EMI-shielded case

APPLICATIONS

Fast detection with large area photodiodes | Spectroscopy | Photodetection with PMTs and photodiodes | Ionization detectors | Pyro- and piezoelectric detectors

Model	-3 dB Bandwidth (DC ...)	Noise Current [fA/√Hz]	Transimpedance (Gain)	Rise/Fall Time	Max. Source Capacitance
HCA-1M-1M	1 MHz	270 fA	1 x 10 ⁶ V/A	350 ns	50 pF
HCA-1M-1M-C	1 MHz	3.5 pA	1 x 10 ⁶ V/A	350 ns	2 nF
HCA-2M-1M	2 MHz	340 fA	1 x 10 ⁶ V/A	180 ns	25 pF
HCA-2M-1M-C	2 MHz	3.5 pA	1 x 10 ⁶ V/A	180 ns	1 nF
HCA-4M-500K	4 MHz	490 fA	5 x 10 ⁵ V/A	90 ns	15 pF
HCA-4M-500K-C	4 MHz	3.5 pA	5 x 10 ⁵ V/A	90 ns	500 pF
HCA-10M-100K	10 MHz	1.1 pA	1 x 10 ⁵ V/A	35 ns	15 pF
HCA-10M-100K-C	10 MHz	3.5 pA	1 x 10 ⁵ V/A	35 ns	150 pF
HCA-20M-100K-C	20 MHz	3.5 pA	1 x 10 ⁵ V/A	18 ns	50 pF
HCA-40M-100K-C	40 MHz	3.7 pA	1 x 10 ⁵ V/A	10 ns	30 pF
HCA-100M-50K-C	100 MHz	3.8 pA	5 x 10 ⁴ V/A	3.5 ns	20 pF*
HCA-200M-20K-C	200 MHz	4.9 pA	2 x 10 ⁴ V/A	1.9 ns	8 pF*
HCA-400M-5K-C	400 MHz	21 pA	5 x 10 ³ V/A	1 ns	10 pF*

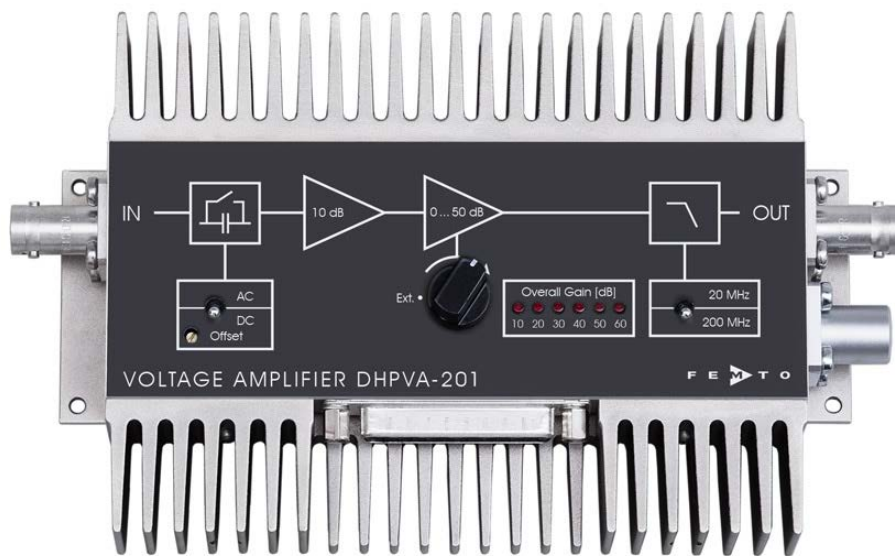
Output voltage ±1.5 V, @ 50 Ω load. Offset adjustable by trimpot. Output short-circuit protected. Adjustable bias-output (-12 V ... +12 V) for biasing photodiodes. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

NOTE: The maximum detector capacitance listed above means that up to this value the specified -3dB-bandwidth (±15 %) is guaranteed. Larger capacitances are also possible, but will slightly influence the bandwidth and frequency response.

* For the ultra fast models HCA-100M-50K-C, HCA-200M-20K-C and HCA-400M-5K-C a reduction in bandwidth up to 25 % of the nominal values might occur if the source capacitance reaches the above noted maximum source capacitance values. Especially for these models short cables at the input and the use of low capacitance sources is of major importance. For further information please view the datasheet or contact FEMTO®.

VOLTAGE AMPLIFIERS

Variable Gain Wideband Amplifiers



CURRENT AMPLIFIERS

VOLTAGE AMPLIFIERS

GHZ-WIDEBAND
AMPLIFIERS

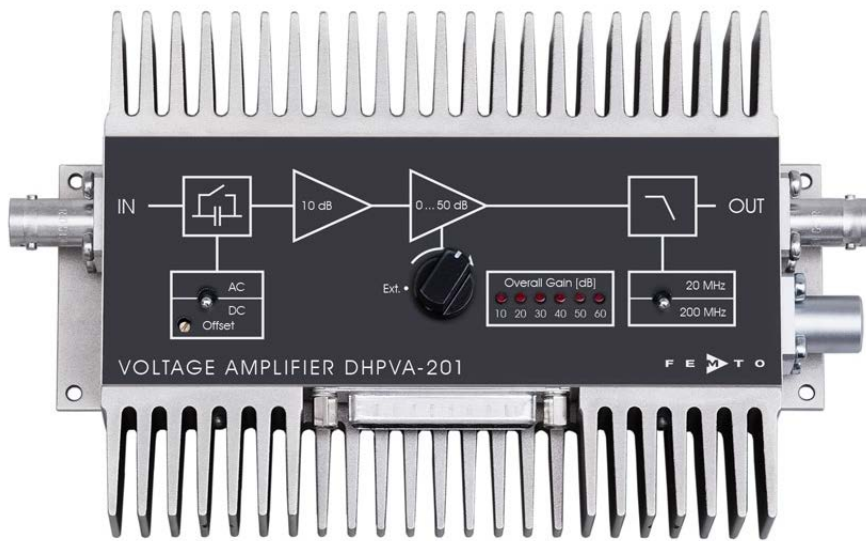
PHOTORECEIVERS

LOCK-IN AMPLIFIERS

ACCESSORIES

SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

DHPVA Series 100/200 MHz Wideband Voltage Amplifiers



- Bandwidth DC to 100 or 200 MHz independent of chosen gain setting
- Variable gain from 10 to 60 dB ($\times 3$ to $\times 1,000$)
- Input noise 2.3 nV/ $\sqrt{\text{Hz}}$
- DC drift only 0.3 $\mu\text{V}/^\circ\text{C}$
- True DC coupling, switchable to AC
- Switchable 10 or 20 MHz low pass filter for minimizing wide band noise
- Local and remote control

APPLICATIONS

Oscilloscope and transient recorder preamplifier | Photomultiplier amplifier | Signal booster for optical receivers and current amplifiers | Time-resolved pulse and transient measurements | Automated measurement systems

HVA Series Wideband Voltage Amplifiers

- Bandwidth DC to 10, 200 or 500 MHz
- Fixed or variable gain up to 60 dB ($\times 1,000$)
- Noise down to 0.9 nV/ $\sqrt{\text{Hz}}$
- True DC coupling, switchable to AC
- 50 Ω bipolar or 1 M Ω FET input stage

APPLICATIONS

Oscilloscope and transient recorder preamplifier | Photomultiplier and microchannel plate amplifier | Time-resolved pulse and transient measurements | Amplification of digital signals (no baseline shift at any digital code)



DLPVA Series Low-Frequency Voltage Amplifiers



- Bandwidth DC to 100 kHz
- Variable gain up to 100 dB ($\times 100,000$)
- Input noise down to 0.4 nV/ $\sqrt{\text{Hz}}$
- DC-drift down to 0.5 $\mu\text{V}/^\circ\text{C}$
- True DC coupling, switchable to AC
- Input impedance up to 1 T Ω
- Local and remote control

APPLICATIONS

Universal low-frequency amplifier | Automated measurements | Industrial sensors | Detector preamplifier | Integrated measurement systems

For detailed information about DHPVA-, HVA-, and DLPVA-series see next page!

DHPVA Series Reference Class from DC to 200 MHz

Model	DHPVA-101	DHPVA-201
Lower Cut-Off Frequency	DC/10 Hz, switchable	DC/10 Hz, switchable
Upper Cut-Off Frequency	10/100 MHz, switchable	20/200 MHz, switchable
Gain [dB]	10/20/30/40/50/60, switchable	10/20/30/40/50/60, switchable
Input Voltage Noise	2.3 nV/√Hz	2.3 nV/√Hz
Input Voltage Drift	0.3 μV/°C	0.3 μV/°C
Input/Output	50 Ω, BNC	50 Ω, BNC
Input Return Loss S11	-31 dB @ 100 MHz	-22 dB @ 200 MHz
Output Return Loss S22	-35 dB @ 100 MHz	-30 dB @ 200 MHz
Output Voltage	±1 V @ 50 Ω	
Monitor Output	DC - 100 kHz monitor output at D-Sub connector, gain of 1	
Digital Control	5 opto-isolated digital inputs, TTL/CMOS compatible	
Power Requirements	±15 V, ±120 mA typ.	
Dimensions	175 x 105 x 45 mm (L x W x H), weight 560 g (1.24 lbs)	

Offset adjustable by trimpot or external control voltage. Indication of selected gain setting by LEDs. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply series PS-15 available. For further information please see the datasheet.

The new improved models DHPVA-101 and DHPVA-201 replace the previous models DHPVA-100 and DHPVA-200. They are fully compatible delivering at least the same or better electrical performance. The heatsinks may be removed if adequate alternative cooling is provided like mounting the amplifier to a sufficiently large case/rack system.

HVA Series True DC-Coupling with Zero Output Offset

Model	HVA-10M-60-B	HVA-10M-60-F	HVA-200M-40-B	HVA-200M-40-F	HVA-500M-20-B
Lower Cut-Off Frequency	DC/1 kHz	DC/1 Hz	DC/1 kHz	DC/1 Hz	DC
Upper Cut-Off Frequency	10 MHz	10 MHz	200 MHz	200 MHz	500 MHz
Gain [dB]	40/60	40/60	20/40	20/40	20
Input Voltage Noise	0.9 nV/√Hz	4.7 nV/√Hz	1.2 nV/√Hz	4.5 nV/√Hz	3.0 nV/√Hz
Input Voltage Drift	1 μV/°C	2 μV/°C	1 μV/°C	5 μV/°C	10 μV/°C
Input	50 Ω, BNC	1 MΩ, BNC	50 Ω, BNC	1 MΩ, BNC	50 Ω, BNC
Output	50 Ω, BNC	50 Ω, BNC	50 Ω, BNC	50 Ω, BNC	50 Ω, BNC
Output Voltage	±3.5 V @ 50 Ω	±3.5 V @ 50 Ω	±1 V @ 50 Ω	±1 V @ 50 Ω	±1 V @ 50 Ω
Power Requirements	±15 V, ±70 mA typ.				
Dimensions	112 x 51 x 33 mm (L x W x H), weight 200 g (0.5 lbs)				

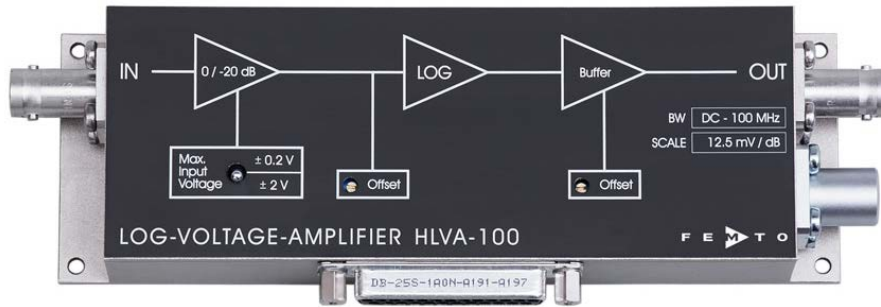
Offset adjustable by trimpot. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

DLPVA Series High Gain up to 100 dB

Model	DLPVA-100-BUN-S	DLPVA-100-BLN-S	DLPVA-100-B-S	DLPVA-100-B-D	DLPVA-100-F-S	DLPVA-100-F-D
Input stage	Single ended, bipolar	Single ended, bipolar	Single ended, bipolar	True diff., bipolar	Single ended, FET	True diff., FET
Input	1 kΩ, BNC	1 MΩ, BNC	1 MΩ, BNC	1 MΩ, Lemo®	1 TΩ, BNC	1 TΩ, Lemo®
Typical Source Impedance	<50 Ω	<100 Ω	<1 kΩ	<1 kΩ	<1 GΩ	<1 GΩ
Lower Cut-Off Frequency	1.5 Hz (AC only)	DC/1.5 Hz	DC/1.5 Hz	DC/1.5 Hz	DC/1.5 Hz	DC/1.5 Hz
Upper Cut-Off Frequency	1/100 kHz	1/100 kHz	1/100 kHz	1/100 kHz	1/100 kHz	1/100 kHz
Gain [dB]	40/60/80/100	40/60/80/100	20/40/60/80	20/40/60/80	20/40/60/80	20/40/60/80
Input Voltage Noise	0.4 nV/√Hz	0.7 nV/√Hz	2.4 nV/√Hz	3.6 nV/√Hz	5.5 nV/√Hz	6.9 nV/√Hz
Input Voltage Drift	-	0.5 μV/°C	0.7 μV/°C	0.7 μV/°C	1.3 μV/°C	1.3 μV/°C
CMRR	-	-	-	120 dB max.	-	120 dB max.
Output	<100 Ω, BNC (terminate with > 10 kΩ load for best performance)					
Output Voltage	±10 V (@ > 10 kΩ load)					
Digital Control	3 or 4 digital inputs and 1 digital output, opto-isolated, TTL/CMOS compatible					
Power Requirements	±15 V, ±75 mA typ.					
Dimensions	175 x 51 x 34 mm (L x W x H), weight 320 g (0.7 lbs)					

Offset adjustable by trimpot or external control voltage. Indication of selected gain setting by LED. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

HLVA-100 Logarithmic Wideband Voltage Amplifier



- Wide dynamic range up to 80 dB
- DC coupled, rectifying* input
- Switchable input range from $\pm 20 \mu\text{V}$ to $\pm 200 \text{ mV}$ and from $\pm 200 \mu\text{V}$ to $\pm 2 \text{ V}$
- Rise/fall time 5 ns
- Input noise $2 \text{ nV}/\sqrt{\text{Hz}}$
- Local and remote control
- Integrated sample and hold baseline correction

APPLICATIONS

LIDAR systems | Signal compression | Time-resolved pulse and transient measurements | Mass spectroscopy | Particle detection

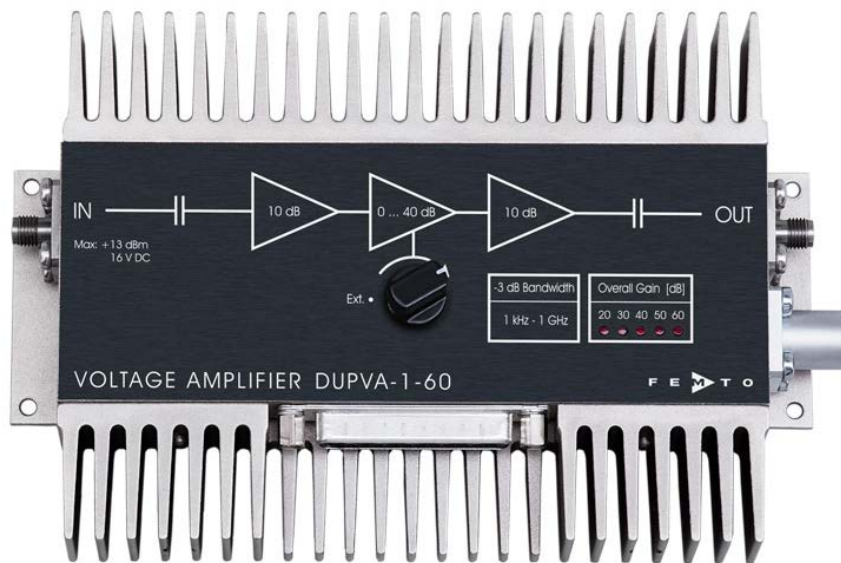
Model	HLVA-100	
Input Voltage Range	from $\pm 20 \mu\text{V}$ to $\pm 200 \text{ mV}$ and from $\pm 200 \mu\text{V}$ to $\pm 2 \text{ V}$, switchable	
Dynamic Range	Typ. 60 dB (for accurate amplitude measurement) Max. 80 dB (for signal detection)	
Scaling	12.5 mV/dB, 250 mV/decade (@ 50 Ω load)	
Linearity	$\pm 1 \text{ dB}$ (for pulse of min. 20 ns pulse width)	
Input Voltage Noise	$2 \text{ nV}/\sqrt{\text{Hz}}$	
Input Voltage Drift	$0.6 \mu\text{V}/^\circ\text{C}$	
Input/Output	50 Ω , BNC	
Rise/Fall Time	5 ns @ 40 dB step	
Output Voltage Range	+50 to +1075 mV typ. @ 50 Ω load (if output is adjusted to 1 V at 100 mV input)	
Output Offset Voltage Range	$\pm 500 \text{ mV}$, adjustable by offset-trimpot	
Baseline Correction	Acquisition time	30 μs (min. sample pulse width)
	Baseline hold droop rate	1 $\mu\text{V}/\text{s}$ (typ. @ 25 $^\circ\text{C}$)
	Loop cut-off frequency	1.5 kHz
Digital Control	2 opto-isolated digital inputs, TTL/CMOS compatible	
Power Requirements	$\pm 15 \text{ V}$, +90 mA/-120 mA typ.	
Dimensions	171 x 57 x 34 mm (L x W x H), weight 320 g (0.7 lbs)	

Offset adjustable by trimpot or external control voltage. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

*The logarithm of a negative number is not defined as real number. Therefore the negative part of an input signal is rectified prior to applying the logarithmic amplification.

GHZ-WIDEBAND AMPLIFIERS

Suitable as Current and Voltage Amplifiers



CURRENT AMPLIFIERS

VOLTAGE AMPLIFIERS

GHZ-WIDEBAND
AMPLIFIERS

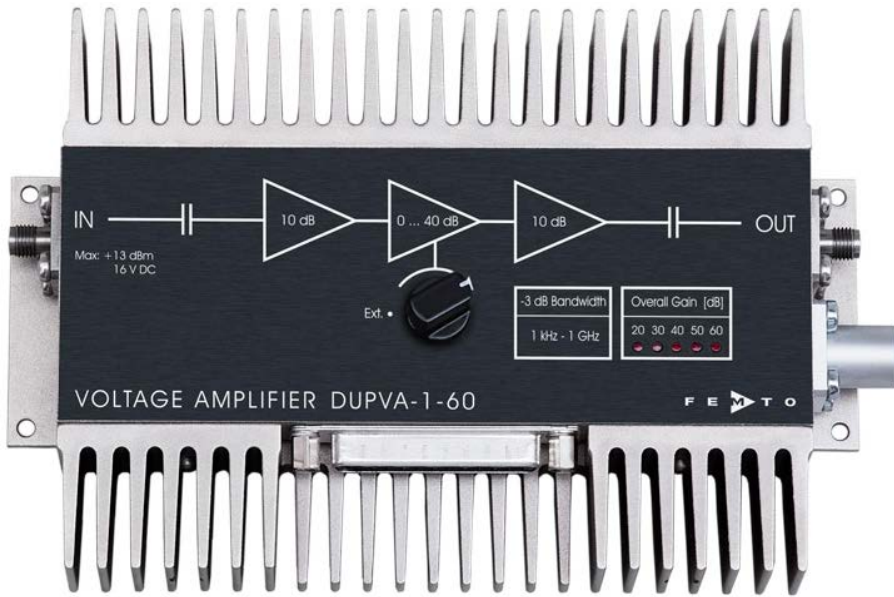
PHOTORECEIVERS

LOCK-IN AMPLIFIERS

ACCESSORIES

SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

DUPVA Series 1 GHz Variable Gain Voltage Amplifiers



- Variable gain up to 70 dB (approx. $\times 3000$), switchable in 10 dB steps
- Bandwidth 1 kHz to 1.2 GHz
- Bandwidth independent of gain setting (guaranteed)
- Noise figure down to 1.9 dB (330 pV/ $\sqrt{\text{Hz}}$)
- Local and remote gain control

APPLICATIONS

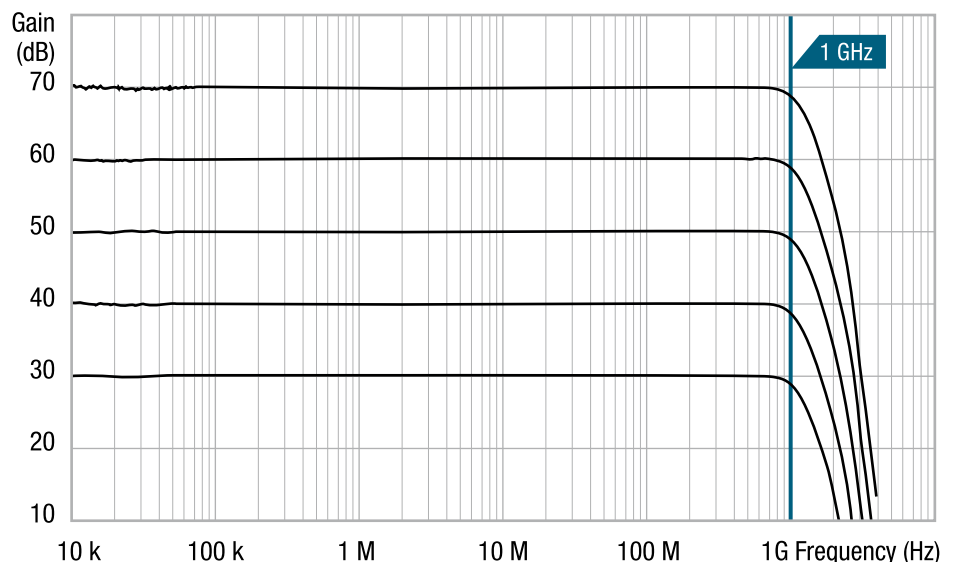
Oscilloscope and transient recorder preamplifier | Photomultiplier and microchannel plate amplifier | Signal booster for optical receivers and current amplifiers | Time-resolved pulse and transient measurements | Automated measurement systems

Model	DUPVA-1-60	DUPVA-1-70
Lower Cut-Off-Frequency	1 kHz	1 kHz
Upper Cut-Off-Frequency	1.2 GHz	1.1 GHz
Rise/Fall Time	380 ps	390 ps
Gain	20/30/40/50/60 dB	30/40/50/60/70 dB
Input Noise	NF 3.0 dB (450 pV/ $\sqrt{\text{Hz}}$)	NF 1.9 dB (330 pV/ $\sqrt{\text{Hz}}$)
Output Power	13 dBm (-1 dB compression @ 100 MHz)	12 dBm (-1 dB compression @ 100 MHz)
Power Requirements	± 15 V, $+350$ mA / -100 mA, typ.	± 15 V, $+250$ mA / -100 mA, typ.
Input/Output	50 Ω , SMA connector	
Monitor Output	DC - 100 kHz monitor output at D-Sub connector, gain of 1	
Control Interface	3 opto-isolated digital inputs, TTL/CMOS compatible	
Dimensions	165 x 105 x 45 mm (L x W x H), weight 510 g (1.1 lbs)	

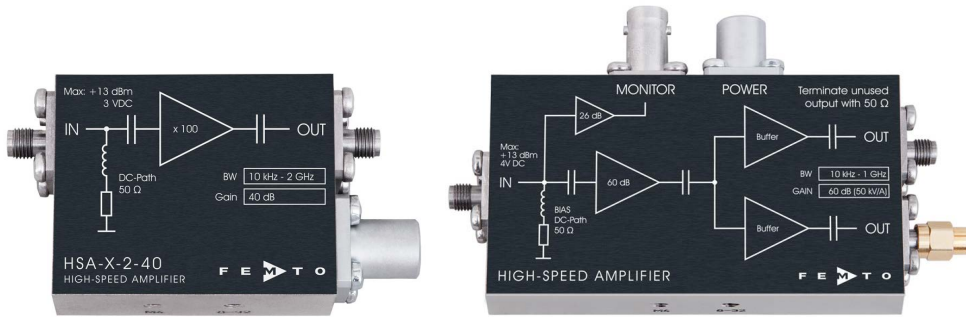
Indication of selected gain setting by LED. Output short-circuit protected. Power supply via 3-pin Lemo[®] socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

TYPICAL PERFORMANCE CHARACTERISTICS

- Bandwidth independent of gain setting (guaranteed), see figure: DUPVA-1-70 gain vs. frequency
- Upper cut-off frequency rolloff: 40 dB/oct.



HSA Series High-Speed GHz Amplifiers



- Ultra-wide bandwidth from 10 kHz up to 2.5 GHz
- Gain up to 60 dB ($\times 1,000$)
- Transimpedance gain with photodetectors up to 50,000 V/A
- Very low input noise down to 310 pV/ $\sqrt{\text{Hz}}$ (6.2 pA/ $\sqrt{\text{Hz}}$)
- Integrated DC-current path for biased photodetector applications

APPLICATIONS

Preamplifier for ultra-fast detectors (microchannel plates, photomultipliers, avalanche photodiodes and PIN photodiodes) | Oscilloscope and spectrum/network analyzer preamplifier | Time-resolved pulse and transient measurements | Signal booster in 50 Ω high-speed systems

Only HSA-Y series:

- Two identical signal outputs
- DC-monitor output

HSA-X Models	HSA-X-1-40	HSA-X-2-20	HSA-X-2-40	HSA-X-1-2-40
Lower Cut-Off-Frequency	10 kHz	10 kHz	10 kHz	10 kHz
Upper Cut-Off-Frequency	1.2 GHz	2.5 GHz	2.0 GHz	2.2 GHz
Rise/Fall Time	290 ps	140 ps	180 ps	160 ps
Gain	40 dB ($\times 100$)	20 dB ($\times 10$)	40 dB ($\times 100$)	40 dB ($\times 100$) inverting
Transimpedance*	5,000 V/A	500 V/A	5,000 V/A	5,000 V/A inverting
Input Noise [$\sqrt{\text{Hz}}$]**	310 pV (6.2 pA)	610 pV (12.2 pA)	620 pV (12.4 pA)	430 pV (8.6 pA)
Input VSWR	1.6 : 1	1.23 : 1	1.4 : 1	1.25 : 1
Maximum Output Voltage @ 50 Ω	2 V _{pp}	2 V _{pp}	1.9 V _{pp}	2 V _{pp}
Output VSWR	1.35 : 1	1.4 : 1	2.5 : 1	1.4 : 1
Power Requirements	+15 V, +140 mA, typ.	+15 V, +105 mA, typ.	+15 V, +125 mA, typ.	+15 V, +140 mA, typ.
Input/Output	50 Ω , SMA			
Dimensions	80 x 45 x 25 mm (L x W x H), weight 100 g (0.23 lb)			

HSA-Y Models	HSA-Y-1-40	HSA-Y-1-60	HSA-Y-2-20	HSA-Y-2-40
Lower Cut-Off-Frequency	10 kHz	10 kHz	10 kHz	10 kHz
Upper Cut-Off-Frequency	1.0 GHz	1.1 GHz	2 GHz	1.9 GHz
Rise/Fall Time	330 ps	320 ps	175 ps	185 ps
Gain	40 dB ($\times 100$)	60 dB ($\times 1,000$)	20 dB ($\times 10$)	40 dB ($\times 100$)
Transimpedance*	5,000 V/A	50,000 V/A	500 V/A	5,000 V/A
Input Noise [$\sqrt{\text{Hz}}$]**	330 pV (6.6 pA)	330 pV (6.6 pA)	680 pV (13.6 pA)	650 pV (13 pA)
Input VSWR	1.45 : 1	1.4 : 1	1.15 : 1	1.2 : 1
Maximum Output Voltage @ 50 Ω	2.0 V _{pp}	2.3 V _{pp}	2.5 V _{pp}	1.7 V _{pp}
Output VSWR	1.6 : 1	1.4 : 1	2.5 : 1	1.8 : 1
Power Requirements	± 15 V, +200 / -10 mA, typ.	± 15 V, +180 / -10 mA, typ.	± 15 V, +160 / -10 mA, typ.	± 15 V, +185 / -10 mA, typ.
Input	50 Ω , SMA			
Output	Two identical signal outputs, 50 Ω , SMA			
Monitor Output	Gain: 26 dB ($\times 20$), transimpedance*: 1 kV/A, output voltage range: ± 10 V ($R_{\text{load}} > 10$ k Ω), bandwidth: DC - 100 kHz			
Dimensions	110 x 70 x 25 mm (L x W x H), weight 180 g (0.41 lb)			

* Transimpedance = Gain \times 50 Ω (Input Impedance)

** Input Noise Current = Input Noise Voltage \div 50 Ω (Input Impedance)

Integrated DC path for use with photodetectors. 8-32 and M4 mounting threads. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

PHOTORECEIVERS

From Femtowatt Sensitivity to Gigahertz Speed



CURRENT AMPLIFIERS

VOLTAGE AMPLIFIERS

GHZ-WIDEBAND
AMPLIFIERS

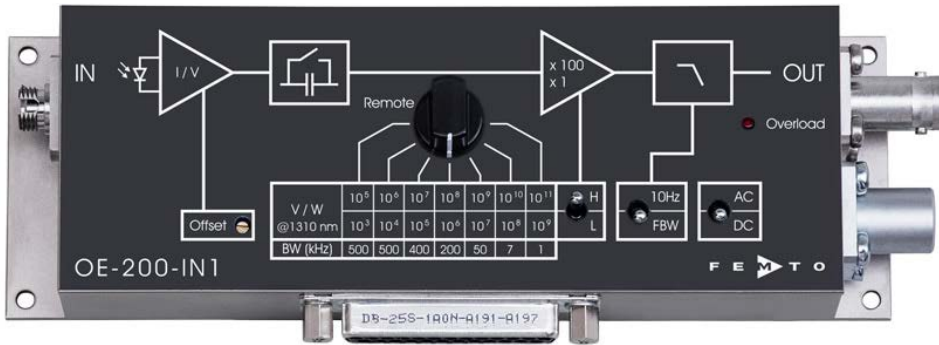
PHOTORECEIVERS

LOCK-IN AMPLIFIERS

ACCESSORIES

SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

OE-200 Series Variable Gain Photoreceivers



- Adjustable conversion gain from 10^3 to 10^{11} V/W
- Operating range from fW to mW
- Spectral range from 190 to 1700 nm
- NEP down to $6 \text{ fW}/\sqrt{\text{Hz}}$
- Bandwidth up to 500 kHz
- Rise time down to 700 ns
- Calibration for all fiber optic models
- Manual and remote control

APPLICATIONS

All purpose lab photoreceiver | Fiber alignment systems | Fast power monitoring | Test of laser diode to fiber coupling | Linearity measurements over 10 decades | Calibration of optical communication systems | Time-resolved pulse and power measurements | Industrial control and alignment systems

Model	OE-200-SI	OE-200-UV	OE-200-IN1	OE-200-IN2
Detector Type	Si-PIN	Si-PIN	InGaAs-PIN	InGaAs-PIN
Detector Size	Ø 1.2 mm	1.1 x 1.1 mm ²	Ø 0.3 mm (FC: Ø 0.08 mm)	Ø 0.3 mm (FC: Ø 0.08 mm)
Spectral Range	320 - 1060 nm	190 - 1000 nm	900 - 1700 nm	900 - 1700 nm
Calibration Wavelength*	850 nm	850 nm	1310 nm	1550 nm
Input Options	FST, FS, FC	FST, FS, FC	FST, FS, FC	FST, FS, FC
NEP (Dependent on Gain Setting)	$8 \text{ fW}/\sqrt{\text{Hz}}$ - $33 \text{ pW}/\sqrt{\text{Hz}}$	$17 \text{ fW}/\sqrt{\text{Hz}}$ - $60 \text{ pW}/\sqrt{\text{Hz}}$	$7 \text{ fW}/\sqrt{\text{Hz}}$ - $22 \text{ pW}/\sqrt{\text{Hz}}$	$6 \text{ fW}/\sqrt{\text{Hz}}$ - $22 \text{ pW}/\sqrt{\text{Hz}}$
Useful Operating Range	ca. 100 fW - 2 mW	ca. 200 fW - 2 mW	ca. 100 fW - 2 mW	ca. 100 fW - 2 mW

The following characteristics are valid for all models:

Performance Range	Low Noise							High Speed						
	10^3	10^4	10^5	10^6	10^7	10^8	10^9	10^5	10^6	10^7	10^8	10^9	10^{10}	10^{11}
Conversion Gain [V/W]**	500	500	400	200	50	7	1.1	500	500	400	200	50	7	1.1
Bandwidth (-3 dB) [kHz]	700 ns	700 ns	900 ns	1.8 µs	7 µs	50 µs	300 µs	700 ns	700 ns	900 ns	1.8 µs	7 µs	50 µs	300 µs
Rise Time (10 % - 90 %)	±1 % electrical between settings, ±5 % electro-optical for FC-input, ±15 % electro-optical for FS- and FST-input													
Accuracy Performance	Switchable to 10 Hz													
Low Pass Filter	±10 V (@ ≥100 kΩ load)													
Output Performance	±15 V, +110 mA/-90 mA typ.													
Power Requirements	5 opto-isolated digital inputs, TTL/CMOS compatible, analog offset control voltage input													
Control Interface	170 x 60 x 45 mm (L x W x H), weight 360 g (0.79 lbs)													
Dimensions														

* Since illumination conditions with the permanently mounted fiber optic connector are well defined, the FC models are delivered with a factory calibrated conversion gain. The electro optical conversion gain factors of the FST and FS free space models are set to fit nominally at the calibration wavelength.

** @ calibration wavelength

Offset adjustable by trimpot or external control voltage. LED overload indication. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

Input Options

FST-Input

Free space input with 1.035"-40 threaded flange, internal threaded coupler ring included



FS-Input

Free space input with unthreaded flange (25 mm diameter)

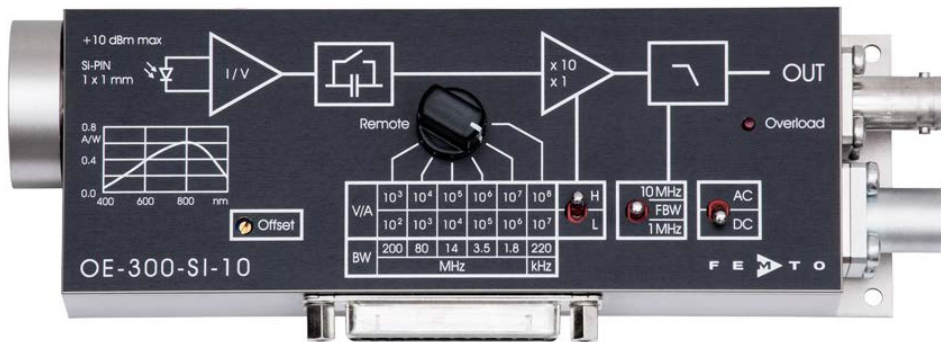


FC-Input

Permanent fiber coupled input



OE-300 Series 200 MHz Variable Gain Photoreceivers



- Adjustable transimpedance gain from 10² to 10⁸ V/A
- Wide bandwidth up to 200 MHz
- Various Si and InGaAs models cover the 320 to 1700 nm wavelength range
- High dynamic input range up to 10 mW optical power
- Large optical detector size up to 3 mm diameter
- Very low noise, NEP down to 47 fW/√Hz
- Switchable low pass filters for minimizing wideband noise
- Full manual and remote control capability

APPLICATIONS

All purpose low-noise photoreceiver (O/E converter) for the MHz range | Time-resolved optical pulse and power measurements | Laser intensity noise measurements (RIN) | Optical front-end for oscilloscopes, spectrum analyzers, A/D converters and RF lock-in amplifiers

Model	OE-300-SI-10	OE-300-SI-30	OE-300-IN-01	OE-300-IN-03
Detector Type	Si-PIN	Si-PIN	InGaAs-PIN	InGaAs-PIN
Detector Size [mm]	1.0 x 1.0	Ø 3.0	Ø 0.08	Ø 0.3
Spectral Range [nm]	400 - 1000	320 - 1000	900 - 1700	800 - 1700
Input Options	FST, FS	FST, FS	FC	FST, FS
NEP (Dependent on Gain Setting)	76 fW/√Hz - 322 pW/√Hz	81 fW/√Hz - 325 pW/√Hz	47 fW/√Hz - 180 pW/√Hz	52 fW/√Hz - 192 pW/√Hz

The following characteristics are valid for all models:

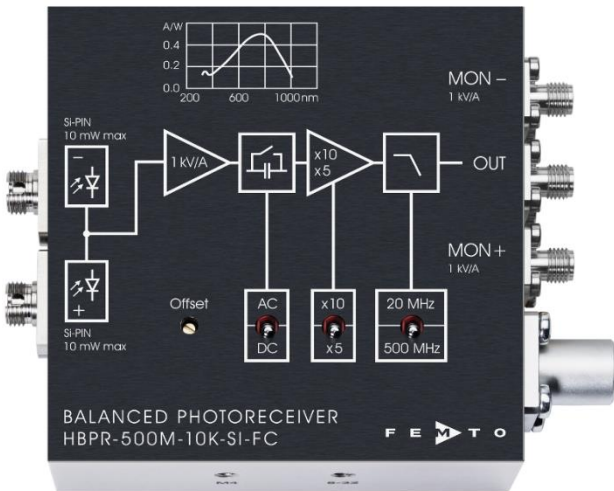
Performance Range	Low Noise						High Speed					
	10 ²	10 ³	10 ⁴	10 ⁵	10 ⁶	10 ⁷	10 ³	10 ⁴	10 ⁵	10 ⁶	10 ⁷	10 ⁸
Gain Setting [V/A] (Transimpedance)	10 ²	10 ³	10 ⁴	10 ⁵	10 ⁶	10 ⁷	10 ³	10 ⁴	10 ⁵	10 ⁶	10 ⁷	10 ⁸
Bandwidth (-3 dB) [MHz]	200 (100) ¹	80 (60) ¹	14	3.5	1.8	0.22	175 (80) ¹	80 (60) ¹	14	3.5	1.8	0.22
Accuracy Performance	±1 % (transimpedance)											
Low Pass Filter	switchable to 1 MHz and 10 MHz											
Output Performance	±1 V (@ 50 Ω load), for linear amplification											
Power Requirements	±15 V, +150 mA/-100 mA typ.											
Control Interface	5 opto-isolated digital inputs, TTL/CMOS compatible, analog offset control voltage input											
Dimensions	170 x 60 x 45 mm (L x W x H), weight 320 g (0.74 lbs)											

¹⁾ model OE-300-SI-30

Offset adjustable by trimpot or external control voltage. LED overload indication. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

Please note! FEMTO® offers fiber connectors (e.g. PRA_FC and PRA-FSMA) which allow connecting the most common types of optical fibers to photoreceivers with FST-input without considerable optical losses. Adapters for optical cables with FC connectors (FC/PC, FC/APC, FC/UPC) and FSMA connectors are available. These are recommended for photosensitive areas of 0.4 mm diameter or more (coupling efficiency may be compromised for photodiodes with smaller diameter).

HBPR-Series Low Noise Balanced Photoreceivers



- Bandwidth up to 500 MHz
- Common-Mode Rejection Ratio (CMRR) up to 55 dB
- Very low noise, NEP down to 3.7 pW/√Hz
- Si and InGaAs models for spectral range from 320 to 1700 nm
- Switchable 20 MHz low pass filter to minimize wideband noise
- High gain of up to 60,000 V/A, switchable in two stages
- Switchable output coupling (AC/DC)
- Fast DC-coupled monitor outputs with 10 MHz bandwidth
- Input either free space or fiber-coupled
- 1.035 "-40 threaded free space input, compatible with many standard optical systems

APPLICATIONS

Optical spectroscopy | Coherent heterodyne detection | Homodyne detection of optical quantum states | Optical coherence tomography (OCT) | Interferometric measurements | Optical delay measurements | Differential optical front end for oscilloscopes, spectrum analyzers, A/D converters and lock-in amplifiers

Input Options

FST-Input



Free space input with 1.035"-40 threaded flange, internal threaded coupler ring included

FS-Input



Free space input with unthreaded flange (25 mm diameter)

FC-Input



Fiber coupled input with fix/permanent FC fiber connector

HBPR models for the spectral range from 320 to 1000 nm:

Model	HBPR-100M-60K-SI-FS HBPR-100M-60K-SI-FST HBPR-100M-60K-SI-FC	HBPR-200M-30K-SI-FS HBPR-200M-30K-SI-FST HBPR-200M-30K-SI-FC	HBPR-500M-10K-SI-FS HBPR-500M-10K-SI-FST HBPR-500M-10K-SI-FC
Si-PIN Photo Diode	0.8 mm Ø	0.8 mm Ø	0.4 mm Ø, FC version with ball lens
Spectral Range	320 - 1000 nm	320 - 1000 nm	320 - 1000 nm
Bandwidth (-3 dB)	DC - 100 MHz	DC - 200 MHz	DC - 500 MHz
Transimpedance Gain (switchable)	2.0 x 10 ⁴ V/A 6.0 x 10 ⁴ V/A	1.0 x 10 ⁴ V/A 3.0 x 10 ⁴ V/A	5.0 x 10 ³ V/A 1.0 x 10 ⁴ V/A
Conversion Gain (switchable)	10.8 x 10 ³ V/W, 32.4 x 10 ³ V/W (typ. @ 850 nm)	5.4 x 10 ³ V/W, 16.2 x 10 ³ V/W (typ. @ 850 nm)	2.55 x 10 ³ V/W, 5.1 x 10 ³ V/W (typ. @ 760 nm)
Minimum NEP	≤ 6.5 pW/√Hz (@850 nm)	≤ 7.8 pW/√Hz (@850 nm)	≤ 12 pW/√Hz (@760 nm)
NEP (@ 20 MHz)	≤ 7.4 pW/√Hz (@850 nm)	≤ 8.8 pW/√Hz (@850 nm)	≤ 13 pW/√Hz (@760 nm)
Common Mode Rejection (typ.)	50 dB	45 dB	40 dB

HBPR-Series Low Noise Balanced Photoreceivers

HBPR models for the spectral range from 800 to 1700 nm:

Model	HBPR-100M-60K-IN-FS HBPR-100M-60K-IN-FST HBPR-100M-60K-IN-FC	HBPR-200M-30K-IN-FS HBPR-200M-30K-IN-FST HBPR-200M-30K-IN-FC	HBPR-450M-10K-IN-FS HBPR-450M-10K-IN-FST HBPR-500M-10K-IN-FC
Si-PIN Photo Diode	0.3 mm Ø (FS/FST model), 80 µm Ø, ball lens (FC model)		
Spectral Range	800 - 1700 nm (FS/FST model), 900 - 1700 nm (FC model)		
Bandwidth (-3 dB)	DC - 100 MHz	DC - 200 MHz	DC - 450 MHz (FS/FST), DC - 500 MHz (FC)
Transimpedance Gain (switchable)	2.0 x 10 ⁴ V/A 6.0 x 10 ⁴ V/A	1.0 x 10 ⁴ V/A 3.0 x 10 ⁴ V/A	5.0 x 10 ³ V/A 1.0 x 10 ⁴ V/A
Conversion Gain (typ. @ 1550nm, switchable)	19 x 10 ³ V/W 57 x 10 ³ V/W	9.5 x 10 ³ V/W 28.5 x 10 ³ V/W	4.75 x 10 ³ V/W 9.5 x 10 ³ V/W
Minimum NEP (@ 1550 nm)	≤ 3.7 pW/√Hz	≤ 4.4 pW/√Hz (FS/FST) ≤ 4.1 pW/√Hz (FC)	≤ 6.5 pW/√Hz (FS/FST) ≤ 6.7 pW/√Hz (FC)
NEP (@ 20 MHz, 1550 nm)	≤ 4.3 pW/√Hz (FS/FST) ≤ 4.0 pW/√Hz (FC)	≤ 4.9 pW/√Hz (FS/FST) ≤ 4.4 pW/√Hz (FC)	≤ 6.9 pW/√Hz
Common Mode Rejection (typ.)	50 dB (FS/FST) 55 dB (FC)	45 dB (FS/FST) 50 dB (FC)	35 dB (FS/FST) 45 dB (FC)

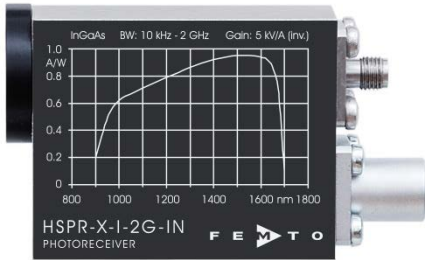
The following characteristics are valid for all HBPR models:

Max. CW Common Mode Power	10 mW on each photo diode
Low Pass Filter	full bandwidth switchable to 20 MHz (upper cut-off frequency)
High Pass Filter (AC coupling)	DC coupling switchable to AC (10 Hz lower cut-off frequency)
Signal Output Voltage	±1.0 V at 50 Ω load (for linear gain and low harmonic distortion), maximum ±2.0 V at 50 Ω load
Monitor Outputs	Transimpedance gain 1000 V/A, bandwidth DC - 10 MHz, output voltage 0 ... +10 V (@ ≥100 kΩ load)
Gain Accuracy	±1 % electrical
Max. Optical CW Balanced Power	10 mW on each photodiode
Power Supply Voltage / Current	±15 V (±14.5 V ... ±16.5 V), -90 / +120 mA typ.
Dimensions	80 x 80 x 30,5 mm (L x B x H), weight FC-models 350 g (0.77 lbs), weight FS/FST-models 410 g (0.9 lbs)

The FST free space SI models with Ø 0.8 mm photodetectors can easily be converted to a fiber connection (FC, FSMA) thanks to the large detector surface, by simply screwing on one optionally available fiber adapter of the PRA series. For models with smaller detector areas, such as Ø 0.4 / 0.3 mm, the use of a fiber adapter is only recommended to a limited extent, since coupling losses and instabilities can occur. If the focus is on high-precision fiber optic measurements, using HBPR FC-models with fixed optical fiber input will usually give the best results.

Offset adjustable by potentiometer. Equipped with UNC 8-32 and M4 threaded holes for integration into optical systems on standard holders. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet or contact FEMTO.

HSPR-X and HSA-X-S Series Ultra-Fast Photoreceivers



- Wavelength range from 320 to 1700 nm
- Ultra-wide bandwidth from 10 kHz up to 2 GHz
- Max. conversion gain 4.75×10^3 V/W
- Min. NEP $11 \text{ pW}/\sqrt{\text{Hz}}$

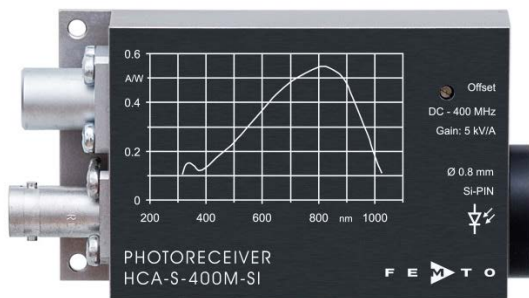
APPLICATIONS

Spectroscopy | Fast pulse and transient measurements | Optical triggering | Optical front-end (O/E converter) for oscilloscopes and A/D converters

Model	HSA-X-S-1G4-SI	HSPR-X-I-1G4-SI (inverting)	HSA-X-S-2G-IN	HSPR-X-I-2G-IN (inverting)
Photodiode	Si-PIN, \varnothing 0.4 mm (FST, FS), integrated ball lens (FC)		InGaAs-PIN, \varnothing 0.1 mm (FST, FS), integrated ball lens (FC)	
Spectral Range	320 - 1000 nm	320 - 1000 nm	900 - 1700 nm	900 - 1700 nm
Bandwidth (-3 dB)	10 kHz - 1.4 GHz	10 kHz - 1.4 GHz	10 kHz - 2 GHz	10 kHz - 2 GHz
Rise/Fall Time (10% - 90%)	250 ps	250 ps	180 ps	180 ps
Transimpedance Gain	5×10^3 V/A	5×10^3 V/A (inverting)	5×10^3 V/A	5×10^3 V/A (inverting)
Conversion Gain	2.55×10^3 V/W (@ 760 nm)	2.55×10^3 V/W (@ 760 nm)	4.75×10^3 V/W (@ 1550 nm)	4.75×10^3 V/W (@ 1550 nm)
NEP (@ 100 MHz)	$32 \text{ pW}/\sqrt{\text{Hz}}$ (@ 760 nm)	$19 \text{ pW}/\sqrt{\text{Hz}}$ (@ 760 nm)	$16 \text{ pW}/\sqrt{\text{Hz}}$ (@ 1550 nm)	$11 \text{ pW}/\sqrt{\text{Hz}}$ (@ 1550 nm)
Output VSWR	2.5 : 1	1.4 : 1	2.5 : 1	1.4 : 1
Max. Output Voltage @ 50 Ω	1.9 V _{pp}	2.0 V _{pp}	1.9 V _{pp}	2.0 V _{pp}
Output Noise	3.6 mV _{RMS}	2.5 mV _{RMS}	3.6 mV _{RMS}	2.5 mV _{RMS}
Input Options	FST, FS, FC	FST, FS, FC	FST, FS, FC	FST, FS, FC
Power Requirements	+15 V, 130 mA typ.	+15 V, 150 mA typ.	+15 V, 130 mA typ.	+15 V, 150 mA typ.
Dimensions	80 x 42 x 30 mm (L x W x H), weight 100 g (0.23 lbs)			

Output short-circuit protected. Threaded M4 and 8-32 mounting holes for use with standard mounting posts. Power supply +15 V via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

HCA-S-400M Series 400 MHz Photoreceivers



- Wavelength range from 320 to 1700 nm
- Bandwidth DC to 400 MHz
- Rise time 1 ns
- Max. conversion gain 4.8×10^3 V/W

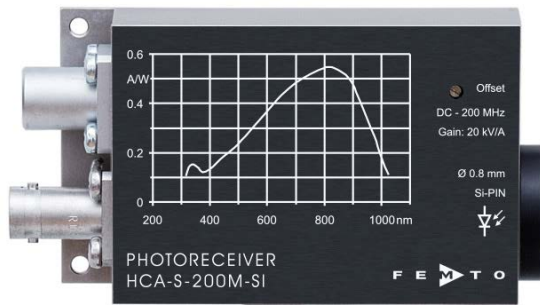
APPLICATIONS

Spectroscopy | Fast pulse and transient measurements | Optical triggering | Test of digital fiber-optic systems | Optical front-end for oscilloscopes and A/D converters

Model	HCA-S-400M-SI	HCA-S-400M-IN
Photodiode	0.8 mm \varnothing Si-PIN	InGaAs-PIN, \varnothing 0.3 mm (FST, FS), integrated ball lens (FC)
Spectral Range	320 - 1000 nm	900 - 1700 nm
Bandwidth (-3 dB)	DC - 400 MHz	DC - 400 MHz
Rise/Fall Time (10% - 90%)	1 ns	1 ns
Transimpedance Gain	5×10^3 V/A	5×10^3 V/A
Max. Conversion Gain	2.7×10^3 V/W (@ 800 nm)	4.8×10^3 V/W (@ 1550 nm)
NEP (@ 100 MHz)	$40 \text{ pW}/\sqrt{\text{Hz}}$ (@ 800 nm)	$24 \text{ pW}/\sqrt{\text{Hz}}$ (@ 1550 nm)
Output Noise	3 mV _{RMS}	3 mV _{RMS}
Input Options	FST, FS, FC, SMA	FST, FS, FC
Power Requirements	± 15 V, ± 55 mA typ.	
Dimensions	100 x 51 x 28 mm, weight 210 g (0.5 lbs)	

Output voltage ± 1.0 V (@ 50 Ω load) for linear amplification. Offset adjustable by potentiometer. Output short-circuit protected. Photoreceivers with free space input come with threaded M4 and 8-32 mounting holes for use with standard mounting posts. Power supply ± 15 V via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

HCA-S-200M Series 200 MHz Photoreceivers



- Wavelength range from 320 to 1700 nm
- Bandwidth from DC to 200 MHz
- Max. conversion gain 1.9×10^4 V/W
- Min. NEP $5.2 \text{ pW}/\sqrt{\text{Hz}}$

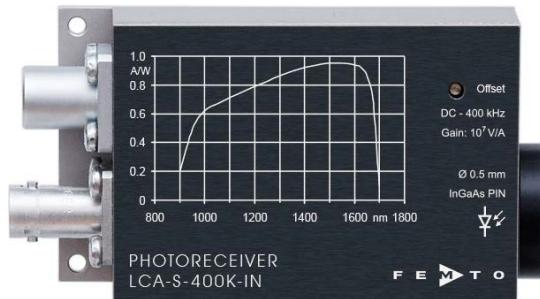
APPLICATIONS

Spectroscopy | Fast pulse and transient measurements |
Optical triggering | Optical front-end for oscilloscopes,
A/D converters and RF lock-in amplifiers

Model	HCA-S-200M-SI	HCA-S-200M-IN
Photodiode	0.8 mm Ø Si-PIN	InGaAs-PIN, Ø 0.3 mm (FST, FS), integrated ball lens (FC)
Spectral Range	320 - 1000 nm	900 - 1700 nm
Bandwidth (-3 dB)	DC - 200 MHz	DC - 200 MHz
Rise/Fall Time (10 % - 90 %)	1.8 ns	1.8 ns
Transimpedance Gain	2×10^4 V/A	2×10^4 V/A
Max. Conversion Gain	1.1×10^4 V/W (@ 800 nm)	1.9×10^4 V/W (@ 1550 nm)
NEP (@ 10 MHz)	$9.4 \text{ pW}/\sqrt{\text{Hz}}$ (@ 800 nm)	$5.2 \text{ pW}/\sqrt{\text{Hz}}$ (@ 1550 nm)
Output Noise	$3 \text{ mV}_{\text{RMS}}$	$4.5 \text{ mV}_{\text{RMS}}$
Input Options	FST, FS, FC, SMA	FST, FS, FC
Power Requirements	$\pm 15 \text{ V}$, $\pm 50 \text{ mA}$ typ.	$\pm 15 \text{ V}$, $\pm 60 \text{ mA}$ typ.
Dimensions	105 x 51 x 28 mm, weight 210 g (0.5 lbs)	

Output voltage $\pm 1.2 \text{ V}$ (@ 50Ω load) for linear amplification. Offset adjustable by potentiometer. Output short-circuit protected. The photoreceivers with free space input come with threaded M4 and 8-32 mounting holes for use with standard mounting posts. Power supply $\pm 15 \text{ V}$ via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

LCA-S-400K Series 400 kHz Photoreceivers



- Wavelength range from 400 to 1700 nm
- Bandwidth from DC to 400 kHz
- Max. conversion gain 10^7 V/W
- Min. NEP $75 \text{ fW}/\sqrt{\text{Hz}}$

APPLICATIONS

Spectroscopy | General purposes opto-electronic measurements | Optical front-end for oscilloscopes,
A/D converters and lock-in amplifiers

Model	LCA-S-400K-SI	LCA-S-400K-IN
Photodiode	3.0 mm Ø Si-PIN	0.5 mm Ø InGaAs-PIN
Spectral Range	400 - 1100 nm	900 - 1700 nm
Bandwidth (-3 dB)	DC - 400 kHz	DC - 400 kHz
Rise/Fall Time (10 % - 90 %)	$1 \mu\text{s}$	$1 \mu\text{s}$
Transimpedance Gain	1×10^7 V/A	1×10^7 V/A
Max. Conversion Gain	5.9×10^6 V/W (@ 920 nm)	9.5×10^6 V/W (@ 1550 nm)
NEP (@ 10 kHz)	$120 \text{ fW}/\sqrt{\text{Hz}}$ (@ 920 nm)	$75 \text{ fW}/\sqrt{\text{Hz}}$ (@ 1550 nm)
Output Noise	$1.6 \text{ mV}_{\text{RMS}}$	$2 \text{ mV}_{\text{RMS}}$
Input Options	FST, FS	FST, FS
Power Requirements	$\pm 15 \text{ V}$, $\pm 40 \text{ mA}$ typ.	
Dimensions	100 x 51 x 28 mm, weight 210 g (0.5 lbs)	

Output voltage $\pm 10 \text{ V}$ max (@ $100 \text{ k}\Omega$ load). Offset adjustable by trimpot. Units with fiber optic input are optionally available. Output short-circuit protected. Threaded M4 and 8-32 mounting holes for use with standard mounting posts. Power supply $\pm 15 \text{ V}$ via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

Mounting options

- The series HSPR-X/HSA-X-S, HCA-S, LCA-S, FWPR and PWPR feature both UNC 8-32 and M4 tapped holes for mounting on metric and imperial threaded standard posts.
- Optional post adapter plate PRA-PAP adds additional UNC 8-32 and M4 tapped holes to the series OE, HCA-S, LCA-S, FWPR and PWPR.

FWPR-20 Series Femtowatt Photoreceivers



APPLICATIONS

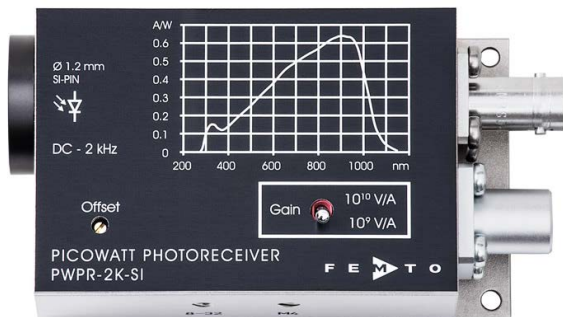
Fluorescence measurements | Spectroscopy | Electrophoresis | Chromatography | Replacement for photomultiplier tubes (PMTs), avalanche photodiodes (APDs) and liquid nitrogen cooled germanium photodiodes

- Ultra-low-noise: NEP 0.7 fW/√Hz
- Wavelength range from 320 nm to 1700 nm
- Bandwidth DC to 20 Hz
- Transimpedance amplifier with high gain up to 10¹² V/A included

Model	FWPR-20-SI	FWPR-20-IN
Photodiode	1.1 x 1.1 mm ² Si	0.5 mm Ø InGaAs-PIN
Spectral Range	320 - 1100 nm	900 - 1700 nm
Bandwidth (-3 dB)	DC - 20 Hz	DC - 20 Hz
Rise/Fall Time (10 % - 90 %)	18 ms	18 ms
Transimpedance Gain	1 x 10 ¹² V/A	1 x 10 ¹¹ V/A
Max. Conversion Gain	0.6 x 10 ¹² V/W (@ 960 nm)	0.95 x 10 ¹¹ V/W (@ 1550 nm)
NEP (@ 1 Hz)	0.7 fW/√Hz (@ 960 nm)	7.5 fW/√Hz (@ 1550 nm)
Output Noise	6 mV _{RMS}	3 mV _{RMS}
Input Options	FST, FS	FST, FS
Power Requirements	±15 V, ±15 mA typ.	
Dimensions	100 x 51 x 28 mm, weight 190 g (0.42 lbs)	

Output voltage ±10 V max (@ 100 kΩ load). Offset adjustable by potentiometer. Units with fiber optic input are optionally available. Output short-circuit protected. Threaded M4 and 8-32 mounting holes for use with standard mounting posts. Power supply ±15 V via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

PWPR-2K Series Picowatt Photoreceivers



APPLICATIONS

Spectroscopy, reflection and transmission measurements | Time-resolved optical pulse and power measurements | Characterization of light sources | Highly sensitive applications using chopper modulation | Optical front-end for oscilloscopes, A/D converters and lock-in amplifiers

- Ultra-low-noise: NEP ≤ 10 fW/√Hz
- Wavelength range from 320 to 1700 nm
- Bandwidth DC to 2 kHz
- Transimpedance gain switchable 10⁹ V/A, 10¹⁰ V/A

Model	PWPR-2K-SI	PWPR-2K-IN
Photodiode	1.2 mm Ø Si-PIN	0.5 mm Ø InGaAs-PIN
Spectral Range	320 - 1060 nm	900 - 1700 nm
Bandwidth (-3 dB)	DC - 2 kHz	DC - 2 kHz
Rise/Fall Time (10 % - 90 %)	165 µs	165 µs
Transimpedance Gain (switchable)	1 x 10 ⁹ V/A 1 x 10 ¹⁰ V/A	1 x 10 ⁹ V/A 1 x 10 ¹⁰ V/A
Max. Conversion Gain	0.64 x 10 ⁹ V/W (@ 900 nm, gain 10 ⁹ V/A) 0.64 x 10 ¹⁰ V/W (@ 900 nm, gain 10 ¹⁰ V/A)	1.1 x 10 ⁹ V/W (@ 1580 nm, gain 10 ⁹ V/A) 1.1 x 10 ¹⁰ V/W (@ 1580 nm, gain 10 ¹⁰ V/A)
NEP (@ 100 Hz)	9 fW/√Hz (@ 900 nm)	10 fW/√Hz (@ 1580 nm)
Output Noise	0.45 mV _{RMS} @ 10 ⁹ V/A	0.75 mV _{RMS} @ 10 ⁹ V/A
Input Options	FST, FS	FST, FS
Power Requirements	±15 V, +32 mA / -25 mA	
Dimensions	100 x 51 x 33 mm, 220 g (0.49 lbs)	

Output voltage ±10 V max (@ 100 kΩ load). Offset adjustable by potentiometer. Output short-circuit protected. Power supply ±15 V via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

LOCK-IN AMPLIFIERS

Easy-to-Use High-Performance Lock-In Amplifiers
For Cost-Sensitive Applications



CURRENT AMPLIFIERS

VOLTAGE AMPLIFIERS

GHZ-WIDEBAND
AMPLIFIERS

PHOTORECEIVERS

LOCK-IN AMPLIFIERS

ACCESSORIES

SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

LIA-MV-150 Series Lock-In Amplifier Modules



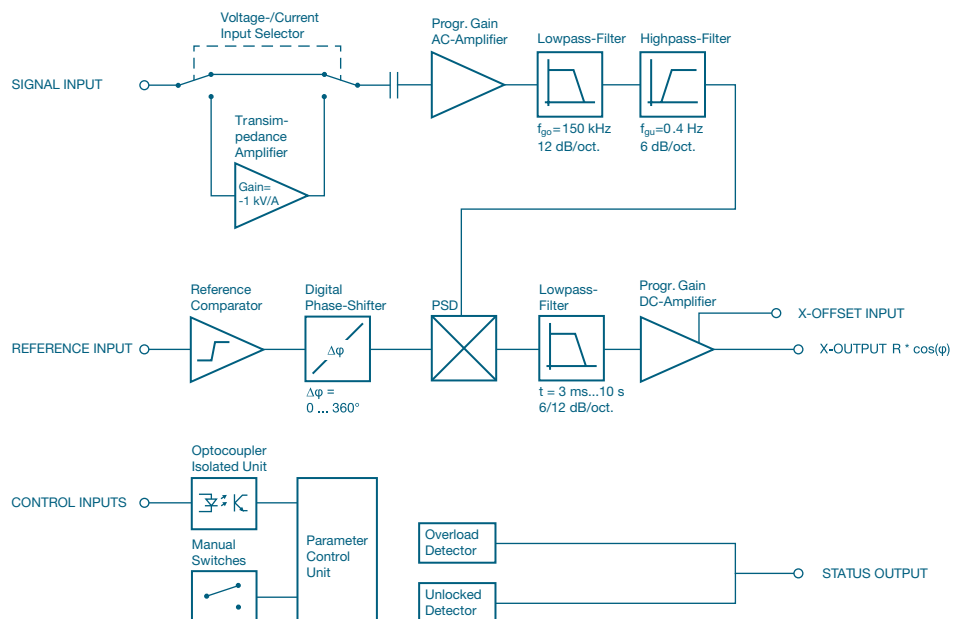
- Current and voltage input
- Working frequency up to 45 kHz
- Adjustable sensitivity, time constant and phase
- Local and remote control
- Compact and EMI-shielded case

Model	LIA-MV-150-S Standard	LIA-MV-150-D True-Differential Input
Voltage Input	BNC connector Single-ended Instrumentation amplifier Noise 12 nV $\sqrt{\text{Hz}}$	Lemo® connector True-differential Instrumentation amplifier Noise 12 nV $\sqrt{\text{Hz}}$
Current Input	BNC connector Transimpedance amplifier, gain 1 kV/A Noise 13 pA $\sqrt{\text{Hz}}$	Lemo® connector Transimpedance amplifier, gain 1 kV/A Noise 13 pA $\sqrt{\text{Hz}}$
Sensitivity (Full Scale)	Voltage: 3 μV to 100 mV, switchable in 1-3-10 steps Current: 3 nA to 100 μA , switchable in 1-3-10 steps	
Working Frequency	10 Hz - 45 kHz	
Reference Input	± 100 mV to ± 5 V, switchable to TTL	
Phase	Adjustable 0° - 360° (8-bit resolution), Temperature drift <0.01°/K	
Demodulator Dynamic Reserve	35 dB @ low drift setting, 55 dB @ high dynamic setting	
Time Constants	3 ms to 10 s, switchable in 1-3-10 steps, slope switchable 6 dB or 12 dB/octave	
Signal Filter	Highpass 0.4 Hz (6 dB/oct.), Lowpass 150 kHz (12 dB/oct.)	
Output	X = in phase, ± 10 V full scale, short-circuit protected	
Digital Control	16 TTL, CMOS, opto-isolated 8-bit phase, 4-bit time constant, 4-bit sensitivity	
Power Supply	± 15 V, 100 mA typ.	
Dimensions	170 x 60 x 30 mm (L x W x H), weight 370 g (0.82 lbs)	

Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

APPLICATIONS

Spectroscopy | Laser stabilization | Luminescence, fluorescence, phosphorescence measurements | Light scattering measurements | Opto-electronical quality control | Integration in industrial and scientific measurement systems | OEM systems



Block diagram LIA-MVD-150

LIA-MV(D)-200 Series Lock-In Amplifiers



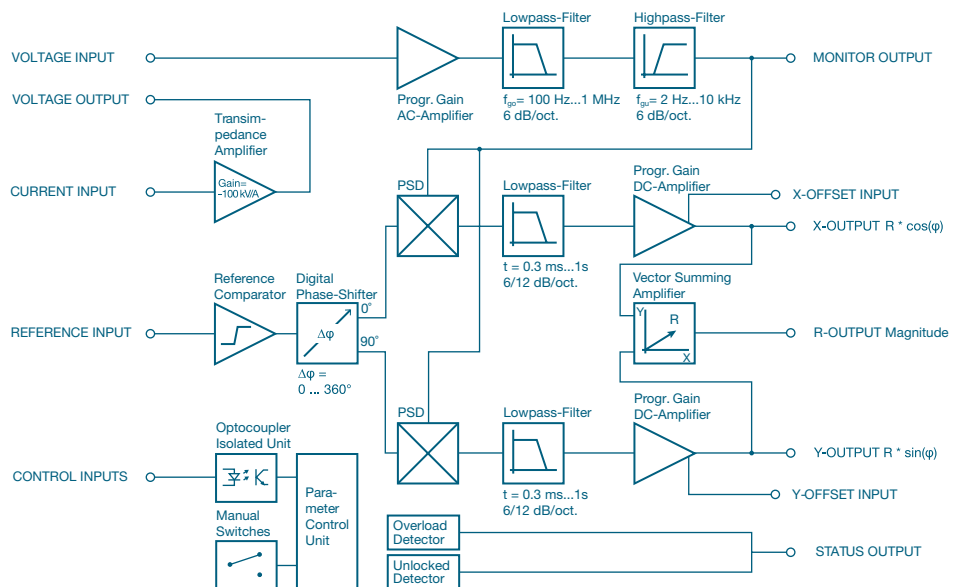
- Single and dual phase
- Rugged aluminum housing
- BNC connectors for input and output signals
- Working frequency 5 Hz up to 120 kHz
- Phase shifter 0° - 360°
- Current and voltage input
- Optional reference oscillator module SOM-1 available

Model	LIA-MV-200-L	LIA-MV-200-H	LIA-MVD-200-L	LIA-MVD-200-H
Working Frequency	Single Phase 5 Hz - 10 kHz	Single Phase 50 Hz - 120 kHz	Dual Phase 5 Hz - 10 kHz	Dual Phase 50 Hz - 120 kHz
Time Constants	3 ms - 10 s 6 or 12 dB/oct.	300 μs - 1 s 6 or 12 dB/oct.	3 ms - 10 s 6 or 12 dB/oct.	300 μs - 1 s 6 or 12 dB/oct.
Adjustable Signal Filter (6 dB/oct.)	Highpass 0.2 Hz - 1 kHz Lowpass 100 Hz - 1 MHz	Highpass 2 Hz - 10 kHz Lowpass 100 Hz - 1 MHz	Highpass 0.2 Hz - 1 kHz Lowpass 100 Hz - 1 MHz	Highpass 2 Hz - 10 kHz Lowpass 100 Hz - 1 MHz
Outputs (BNC)	X = in phase, ±10 V full scale, short-circuit protected, Signal monitor output		X = in phase, Y = quadrature, R = magnitude, ±10 V full scale, short-circuit protected, Signal monitor output	
Sensitivity (Full Scale)	Voltage: 3 μV - 1 V in 1-3-10 steps Current: 30 pA - 10 μA in 1-3-10 steps			
Voltage Input (BNC)	Instrumentation amplifier, noise 12 nV/√Hz			
Current Input (BNC)	Transimpedance amplifier, gain 100 kV/A, noise 0.4 pA/√Hz			
Reference Input (BNC)	±100 mV to ±5 V, switchable to TTL			
Phase	Adjustable 0° - 360°; resolution: 8-bit @ f ≤ 60 kHz, 7-bit @ f > 60 kHz Temperature drift <0.01°/K			
Max. Dyn. Reserve	80 dB			
Digital Control	16 TTL/CMOS inputs: 8-bit phase, 4-bit time constant, 4-bit sensitivity			
Power Supply	±15 V, +120 mA / -60 mA			
Dimensions	223 x 105 x 65 mm (L x W x H), weight 1,000 g (2.2 lbs)			

The optional Reference Oscillator SOM-1 can be connected by an extension connector inside the module. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

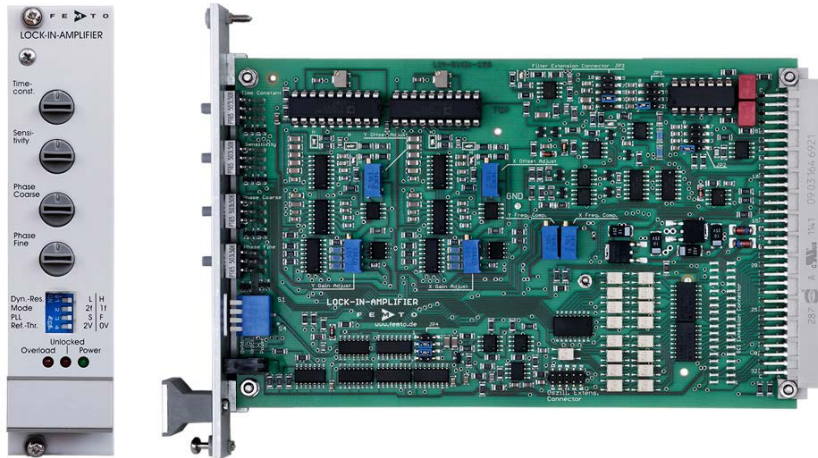
APPLICATIONS

Spectroscopy | Luminescence, fluorescence, phosphorescence measurements | Light scattering measurements | Laser stabilization | Opto-electronical quality control | Integration into industrial and scientific measurement-systems | Alternative to expensive desktop lock-in amplifiers for general lab use



Block diagram LIA-MVD-200-H

LIA-BV(D)-150 Series Single-Board Lock-In Amplifiers



- Single and dual phase 19" boards
- Working frequency 5 Hz up to 120 kHz
- Phase shifter 0° - 360°
- Current and voltage input
- Parameter control by local switches and opto-isolated digital inputs
- Mounting kit MK-LIA-2 and reference oscillator module SOM-1 available

Model	LIA-BV-150-L	LIA-BV-150-H	LIA-BVD-150-L	LIA-BVD-150-H
	Single Phase	Single Phase	Dual Phase	Dual Phase
Working Frequency	5 Hz - 10 kHz	50 Hz - 120 kHz	5 Hz - 10 kHz	50 Hz - 120 kHz
Time Constants	3 ms - 10 s 6 or 12 dB/oct.	300 μ s - 1 s 6 or 12 dB/oct.	3 ms - 10 s 6 or 12 dB/oct.	300 μ s - 1 s 6 or 12 dB/oct.
Signal Filter	Highpass 0.2 Hz - 1 kHz Lowpass 100 Hz - 1 MHz	Highpass 2 Hz - 10 kHz lowpass 100 Hz - 1 MHz	Highpass 0.2 Hz - 1 kHz Lowpass 100 Hz - 1 MHz	Highpass 2 Hz - 10 kHz lowpass 100 Hz - 1 MHz
Outputs	X = in phase, ± 10 V full scale, short-circuit protected, Signal monitor output		X = in phase, Y = quadrature, R = magnitude ± 10 V full scale, short-circuit protected, Signal monitor output	
Sensitivity (Full Scale)	Voltage: 3 μ V - 1 V in 1-3-10 steps Current: 30 pA - 10 μ A in 1-3-10 steps			
Voltage Input	True-differential instrumentation amplifier, noise 12 nV/ \sqrt Hz			
Current Input	Transimpedance amplifier, gain 100 kV/A, noise 0.4 pA/ \sqrt Hz			
Reference Input	± 100 mV to ± 5 V, switchable to TTL			
Phase	Adjustable 0° - 360°; resolution: 8-bit @ $f \leq 60$ kHz, 7-bit @ $f > 60$ kHz Temperature drift $< 0.01^\circ$ /K			
Max. Dyn. Reserve	80 dB			
Digital Control	16 TTL/CMOS inputs: 8-bit phase, 4-bit time constant, 4-bit sensitivity			
Power Supply	± 15 V, +120 mA / -60 mA			
Dimensions	160 x 100 x 20 mm (L x W x H), weight 100 g (0.22 lbs)			

APPLICATIONS

Spectroscopy | Luminescence, fluorescence, phosphorescence measurements | Light scattering measurements | Opto-electronical quality control | Integration in industrial and scientific measurement-systems | Multichannel systems at an attractive price

ACCESSORIES



CURRENT AMPLIFIERS

VOLTAGE AMPLIFIERS

GHZ-WIDEBAND
AMPLIFIERS

PHOTORECEIVERS

LOCK-IN AMPLIFIERS

ACCESSORIES

SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

LUCI-10 USB Control Interface



- Compact digital I/O interface for USB remote control of FEMTO amplifiers and photoreceivers
- Supports opto-isolation of amplifier signal path from PC USB port
- Bus-powered operation
- System driver, application software and VI's for use with LabVIEW™ included

Model	LUCI-10
Bus Interface	USB 2.0 (full-speed)
Digital I/O Interface	16 output lines, 3 opto-isolated input lines
Supply	PC USB bus powered
Connectors	USB type A and D-Sub, 25 pin, male
Case	Zinc die-cast hood, nickel plated, with jack screws, weight 130 g (0.3 lbs)
Software, Included on CD	Device driver for Microsoft® Windows 32 bit & 64 bit operating system, Dynamic link library (DLL), Graphical user interface (GUI) programs, Sample VI's and FEMTO Library for use in LabVIEW™
System Requirements	Microsoft® Windows XP SP 3 or higher, compatible with Windows 10, Intel Pentium III or AMD Athlon or better, 1 GB RAM or more, 5 GB of hard disk space, USB 1.1 or 2.0 port
Optional Requirements	For development of own application programs a development environment like LabVIEW™ Version 2012 (or higher) or C/C++ is required.

PS-15-25-L Remote Power Supply

- Input voltage 100 - 240 VAC
- Output ± 15 V, +500/-400 mA
- Shielded output cord with Lemo® plug
- Floating design to avoid ground loops
- Short-circuit protected
- Ripple typ. 15 mV_{RMS}
- Suitable for all FEMTO modules
- Available as European, Australian and US version



Accessories For Photoreceivers

All FEMTO photoreceivers offered with FS input (round flange with 25 mm diameter) are now also available with 1.035"-40 threaded flange (FST) input – for even more flexibility on the optical bench! For example converting the free-space FST input to an optical fiber input is easily done by screwing on one of the optionally available FEMTO fiber-adapters PRA-FC and PRA-FSMA.

The post adapter plate PRA-PAP expands the optical bread-board mounting options for FEMTO photoreceivers. Even for photoreceivers that are already equipped with post mounting threads the post adapter plate enlarges the mounting position options. Due to the integrated M4 and 8-32 UNC tapped holes, standard posts for breadboard systems can be easily mounted to the photoreceiver via the adapter plate.

The picture shows the PWPR-2K-SI-FST being easily turned into a fiber coupled model.



PRA-FC / PRA-FSMA Fiber-Adapters And Mounting Tool



- Compatible with all FEMTO photoreceivers with threaded 1.035"-40 free space input (FST)
- Easy mounting option for standard optical fibers
- Recommended for photosensitive areas of 0.4 mm diameter or more (coupling efficiency may be compromised for photodiodes with smaller diameter)
- Machined from solid stainless steel
- Available adapter types: PRA-FC (FC/PC, FC/APC, FC/UPC) and PRA-FSMA
- Additionally available: spanner wrench AT-W1 for convenient mounting of the adapters

PRA-PAP Post Adapter Plate



- Compatible with FEMTO photoreceiver series FWPR, PWPR, OE, LCA-S and HCA-S
- M4 and 8-32 UNC threads suitable for standard optical mounting posts
- High-tensile material
- Mounting screws included

CAB-LN1 Series Low Noise Cables



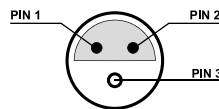
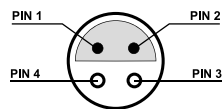
- Minimizes triboelectric and microphonic noise
- Designed for ultra sensitive current and charge measurements
- Noise level reduction by a factor of 1,000
- Highly shielding coaxial design
- Fully assembled with premium quality connectors
- Ultra high insulation resistance > 10¹⁴ Ω – guaranteed
- Variety of lengths available: from 10 cm to 5 m

APPLICATIONS

Measurements of low currents down to femtoamperes | Photodetectors and ionization detectors | High resistance measurements | Scanning probe microscopy (STM, SPM, STS) | Spectroscopy | Piezo- and pyroelectric transducers

Length	Plug BNC – BNC
0.1 m	CAB-LN1-BB-010
0.2 m	CAB-LN1-BB-020
0.5 m	CAB-LN1-BB-050
1.0 m	CAB-LN1-BB-100
1.5 m	CAB-LN1-BB-150
2.0 m	CAB-LN1-BB-200
3.0 m	CAB-LN1-BB-300
5.0 m	CAB-LN1-BB-500

Lemo® Connectors



- High quality connector
- 3-pin and 4-pin versions available
- For use with shielded cables
- Suitable for all FEMTO modules